ZXCT1020
Low offset current output current monitor

Description

The ZXCT1020 is a precision high-side current sense monitor. Using this type of device eliminates the need to disrupt the ground plane when sensing a load current.

The ZXCT1020 uses two external resistors to set the overall voltage gain for applications where improved accuracy at small sense voltages is required. For fixed gain variants Zetex offers the ZXCT1021 (G=10) and ZXCT1022 (G=100).

The ZXCT1020 footprint follows that of the ZXCT1021/2 with only 2 additional resistors required:

One resistor between pins 1 and 4 for setting transconductance, and the other between pins 3 and 2 for setting overall gain.

Current output enables the user to set the gain via these external resistors. Using two external resistors to set the gain ensures optimal versatility as the transconductance can be varied to meet the output impedance requirements of the load that the ZXCT1020 has to drive.

The very low offset voltage enables a typical accuracy of 3% for sense voltages of only 10mV, giving better tolerances for small sense resistors necessary at higher currents.

The wide input voltage range of 20V down to as low as 2.5V make it suitable for a range of applications. With a minimum operating current of just 25μA, combined with its SOT23-5 package make it suitable for portable battery equipment too.

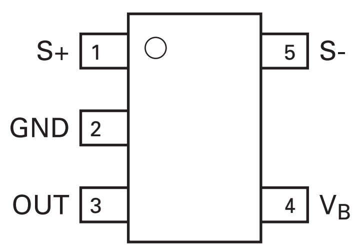
Features

- Accurate high-side current sensing
- Versatile current output scaling
- 2.5V - 20V operating range
- 25μA quiescent current
- 1% typical accuracy
- SOT23-5 package

Applications

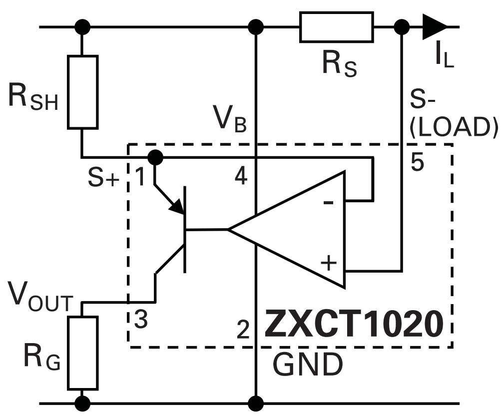
- Battery chargers
- Over-current monitor
- Motherboard power supply current measurement
- Level translating
- Programmable current source

Pinout information



Top view

Typical application circuit



Ordering information

Order reference	Package	Device marking	Status	Reel size (inches)	Quantity per reel	Tape width (mm)
ZXCT1020E5TA	SOT23-5	1020	Preview	7	3000	8

Absolute maximum ratings

Voltage on V_B with respect to GND pin	-0.5V to 20V
Voltage on S+[(a)], S-[(b)], OUT with respect to GND pin	-0.5V to V_B+0.5V
V_{SENSE}[(c)]	-0.5V to +2.5V[(d)]
Junction temperature	-40°C to125°C
Storage temperature	-55°C to 150°C
Package power dissipation (T_{amb} = 25°C) SOT23-5	300mW

NOTES:
(a) Subject to V_{SENSE}+ never going 6V below V_B.
(b) Subject to absolute maximum V_{SENSE} not being exceeded.
(c) V_{SENSE} is defined as the voltage difference across the sense resistor. and is the voltage across resistor R_{SH} plus the voltage between S+ and S-.
(d) V_{SENSE} might need to be reduced when used with smaller values of R_{SH} and at larger rails due to increased power dissipation.

Pin out information

Pin	Name	Pin function
1	S+	Positive sense input. Should be tied to positive side of sense resistor via resistance (R_{SH}) of the order of 150Ω to 1.5kΩ.
2	GND	Ground and substrate connection of device.
3	OUT	Current output. A gain setting resistor (R_G) referenced to GND should be connected to this pin to set overall voltage gain of: Gain = R_G/R_{SH} The resistance, R_G, placed on out will set the ZXCT1020 output impedance equal to R_G. When driving low impedance loads both R_G and R_{SH} should be reduced.
4	V_B	Input voltage pin. Provides bias to current monitor and should be tied to the rail whose current is being monitored.
5	S-	High impedance negative sense voltage input

Recommended operating conditions

Parameter		Min.	Max.	Units
V_{SENSE+}	Common-mode sense input range	2.5	20	V
V_B	Bias pin input voltage range [(*)]	2.5	20	V
V_{SENSE}	Differential sense Input voltage range	0	1.5	V
V_{OUT}	Output voltage range	0	V_{SENSE-} - 1	V
R_{SH}	Shunt resistor value	120	2000	Ω
T_A	Ambient temperature range	-40	85	°C

NOTES:
(*) For best performance V_B and V_{SENSE+} should be referred to the rail whose current is being measured.

Recommended resistor gain setting combinations

Gain	R_{SHUNT}	R_{GAIN}
10	1.5kΩ	15kΩ
20	750Ω	15kΩ
50	300Ω	15kΩ
100	150Ω	15kΩ

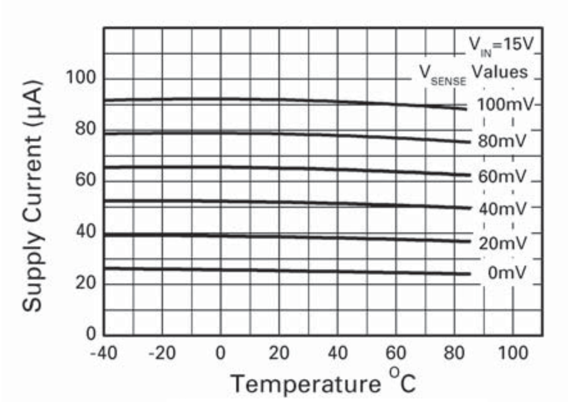
Electrical characteristics

T_{amb} = 25°C, V_{SENSE+} = V_B = 15V, V_{SENSE} = 100mV, R_G = 15kΩ, R_{SH} = 1.5kΩ unless otherwise stated.

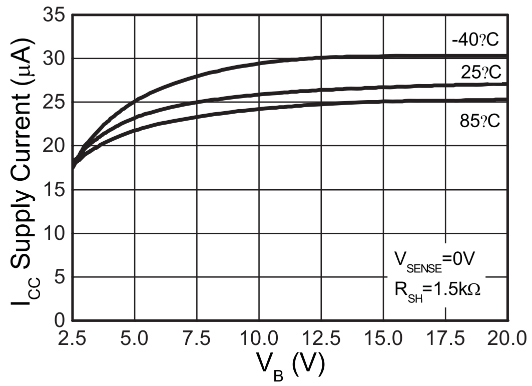
Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ.	Max.	
V_{OUT}	Output voltage	V_{SENSE} = 0mV		3	15	mV
		V_{SENSE} = 30mV	291	300	309	mV
		V_{SENSE} = 100mV	0.98	1	1.02	V
		V_{SENSE} = 150mV	1.47	1.5	1.53	V
TC[1]	Output voltage temperature coefficient			50	300	ppm
I_Q	Ground pin current	V_{SENSE} = 0V		25	35	μA
I_{S-}	S- input current	V_{SENSE} = 0V		20	100	nA
I_{S+}	S+ input current	V_{SENSE} = 0V		100		nA
Acc	Accuracy	V_{SENSE} = 100mV	-2		2	%
Gain	V_{OUT} /V_{SENSE}	V_{SENSE} = 100mV		10		V/V
R_{OUT}	Output resistance	R_G not connected		370		MΩ
BW	Bandwidth	V_{SENSE} (DC) = 10mV		300		kHz
		V_{SENSE} (DC) = 100mV		2		MHz
PSRR	Power supply rejection ratio	V_{SENSE+} = V_B = 2.5 to 20V	70	80		dB

Typical characteristics

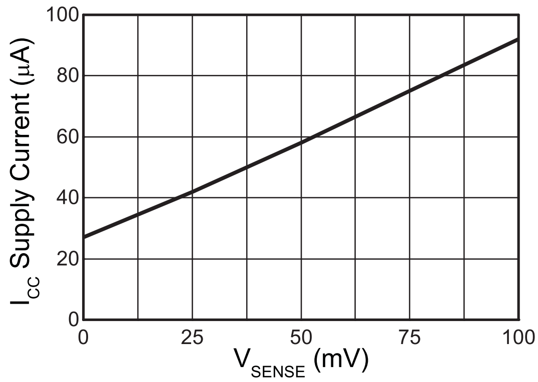
Test conditions unless otherwise stated: T_A = 25°C, V_B = V_{SENSE+} (via R_{SH}) =15V, V_{SENSE} = 100mV R_{SH} = 1.5kΩ, R_G = 15kΩ.



Supply current v Temperature

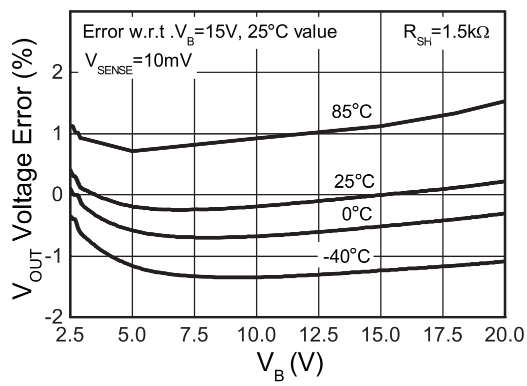


Supply Current v V_B

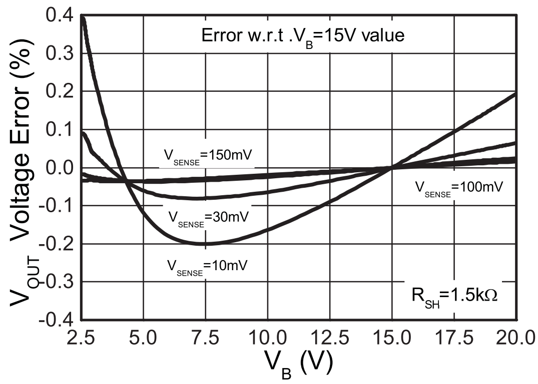


Supply Current v V_{SENSE}

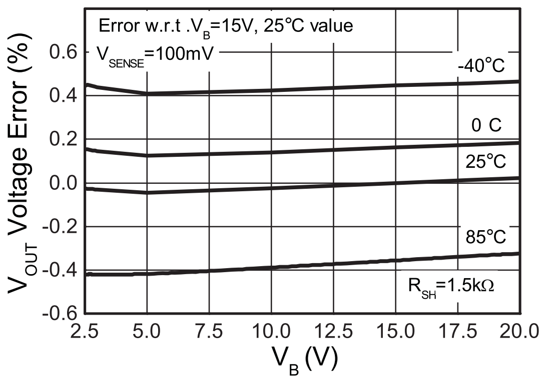
Test conditions unless otherwise stated: T_A = 25°C, $V_B = V_{SENSE+}$ (via R_{SH}) =15V, V_{SENSE} = 100mV Gain = 10, R_G = 15kΩ.



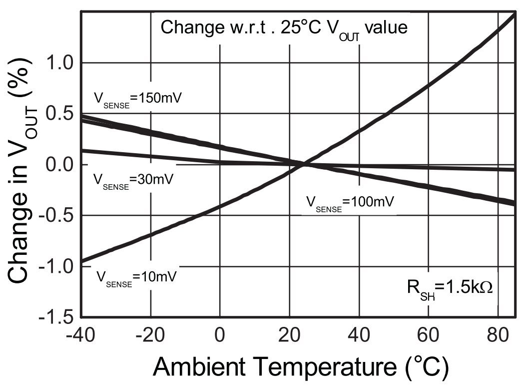
V_{OUT} Voltage Error v V_B



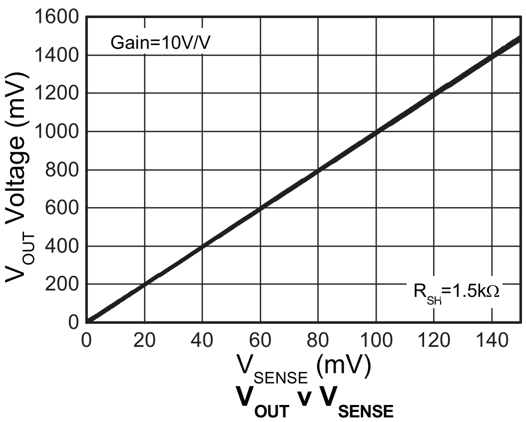
V_{OUT} Voltage Error v V_B



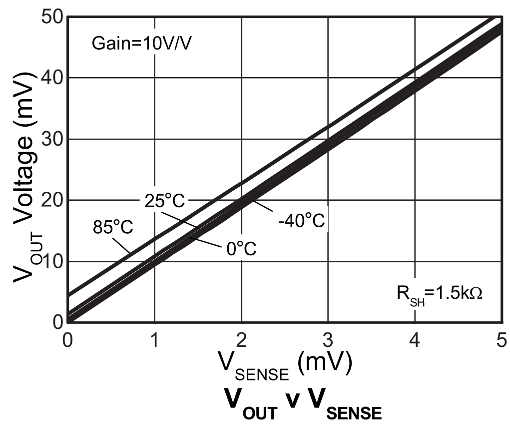
V_{OUT} Voltage Error v V_B



Change in V_{OUT} v Temperature

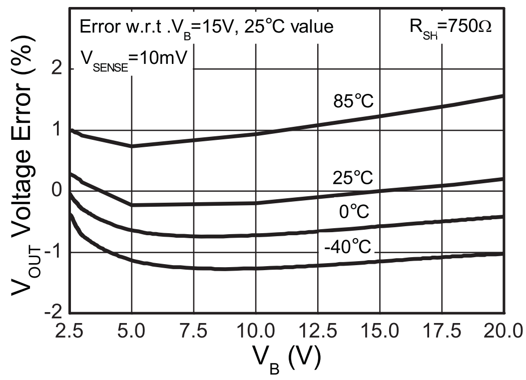


V_{OUT} v V_{SENSE}

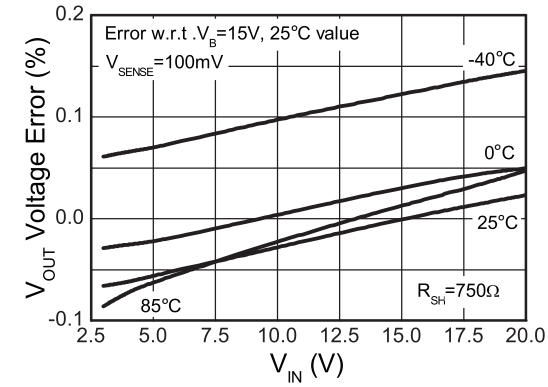


V_{OUT} v V_{SENSE}

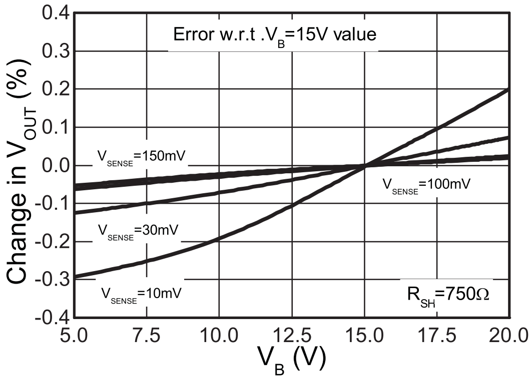
Test conditions unless otherwise stated: T_A = 25°C, V_B = V_{SENSE+} (via R_{SH}) =15V, V_{SENSE} = 100mV Gain = 20, R_G = 15kΩ.



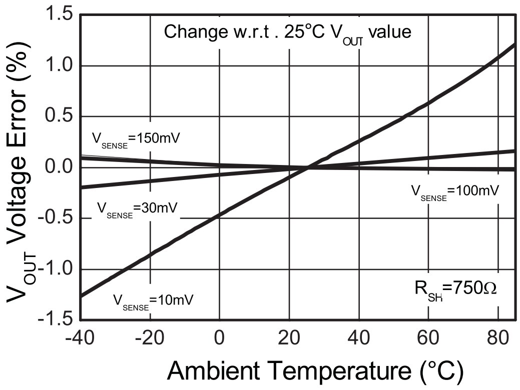
V_{OUT} Voltage Error v V_B



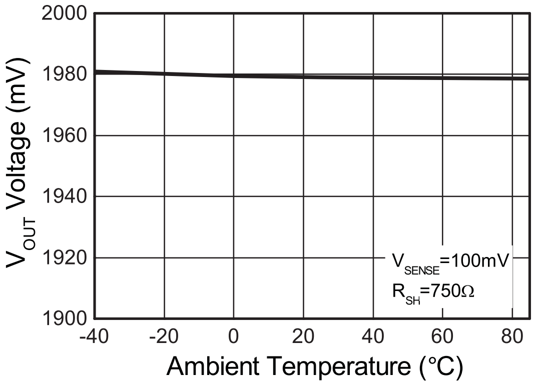
V_{OUT} Voltage Error v V_{IN}



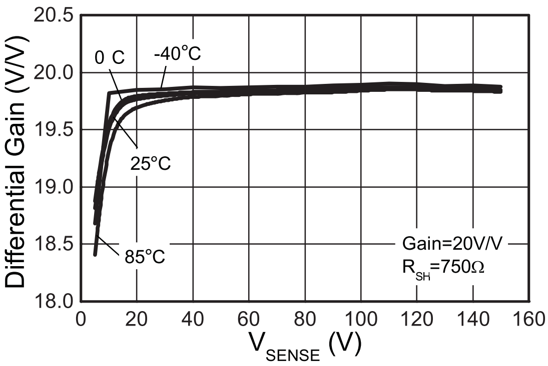
V_{OUT} Voltage Error v V_B



Change in V_{OUT} v Temperature

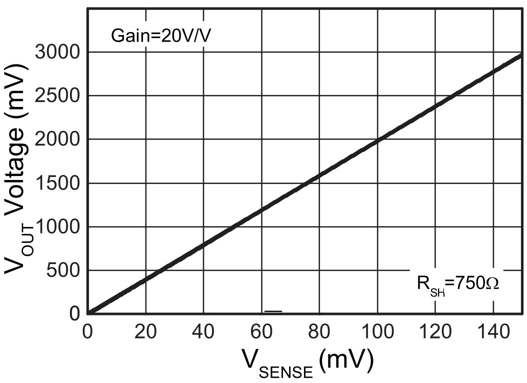


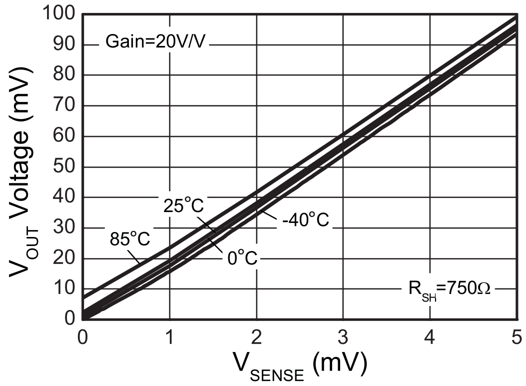
V_{OUT} v Ambient Temperature



Differential Gain v V_{SENSE}

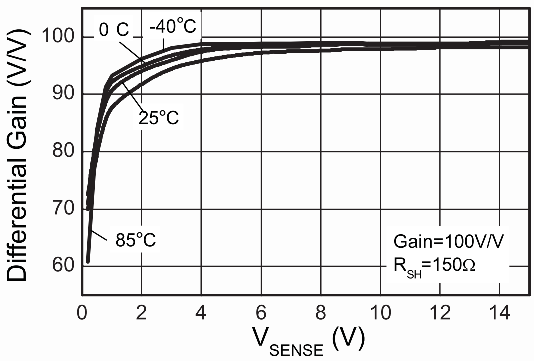
Test conditions unless otherwise stated: T_A = 25°C, V_B = V_{SENSE+} (via R_{SH}) =15V, V_{SENSE} = 100mV R_G = 15kΩ.



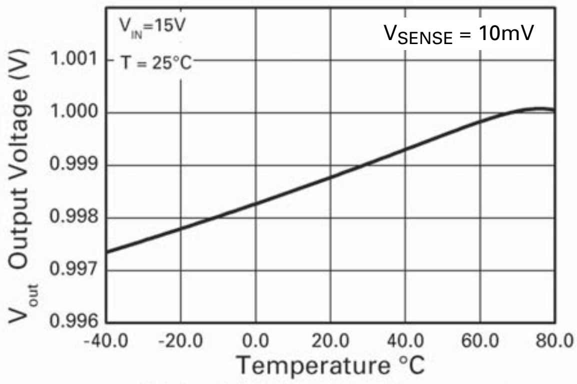


V_{OUT} v V_{SENSE} V_{OUT} v V_{SENSE}

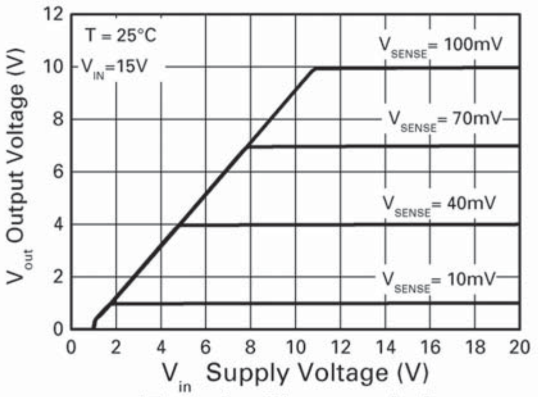
Gain = 100



Differential Gain v V_{SENSE}



Output Voltage v Temperature

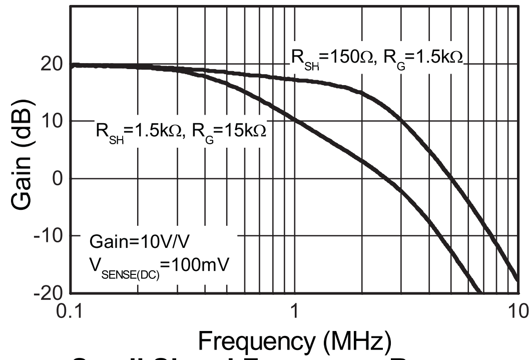


Transfer Characteristic

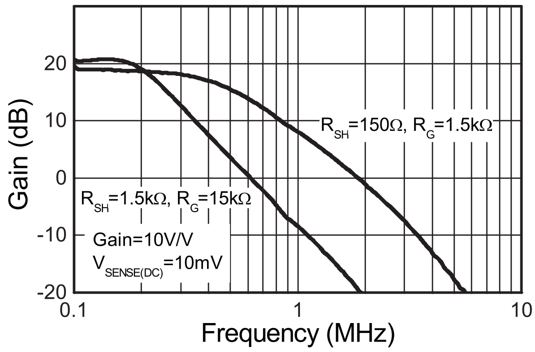
Typical AC characteristics

Test conditions unless otherwise stated: T_A = 25°C, V_B = V_{SENSE+} (via R_{SH}) =15V, V_{SENSE} = 100mV, R_G = 15kΩ.

Gain = 10

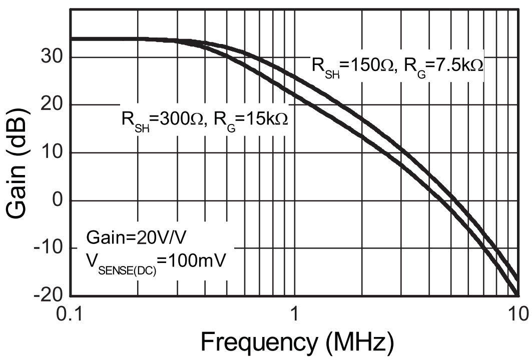


Small Signal Frequency Reponse

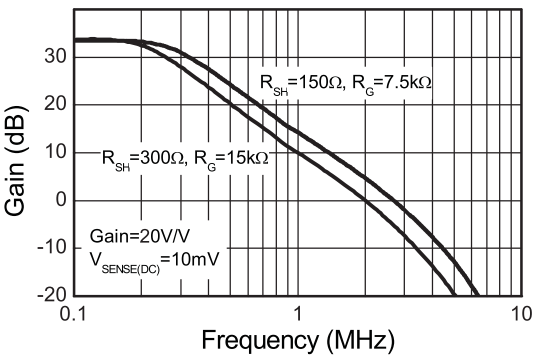


Small Signal Frequency Response

Gain = 50



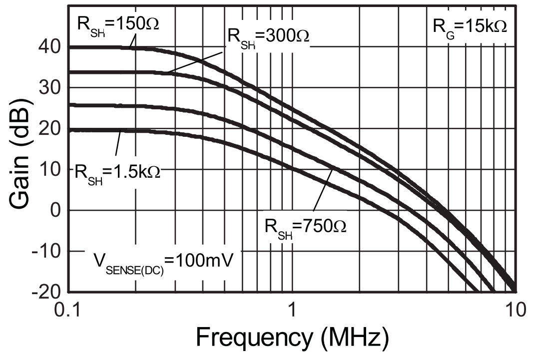
Large Signal Frequency Response



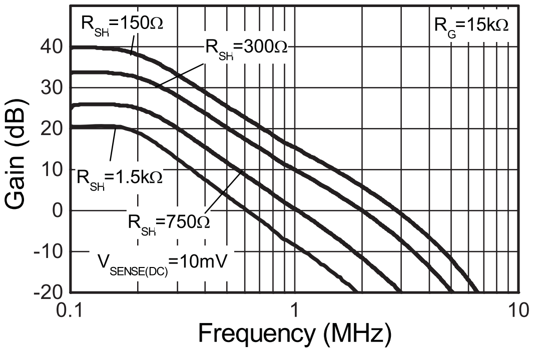
Small Signal Frequency Response

Test conditions unless otherwise stated: T_A = 25°C, R_G=15k, V_B = V_{SENSE+} (via R_{SH}) =15V, V_{SENSE} = 100mV unless otherwise stated.

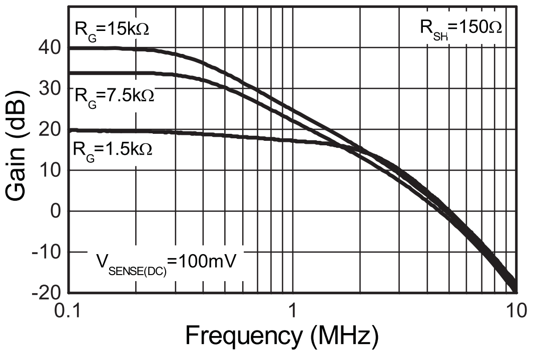
Various gains with constant R_G



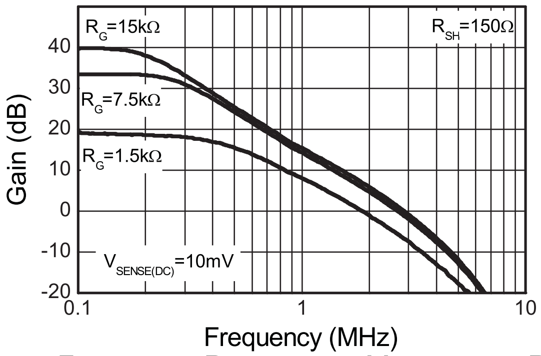
Frequency Response with constant R_G



Frequency Response with constant R_G

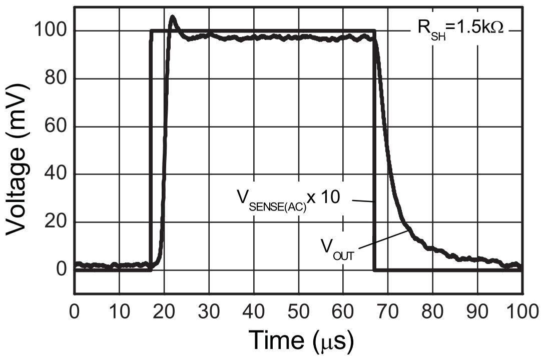


Frequency Response with constant R_{SH}

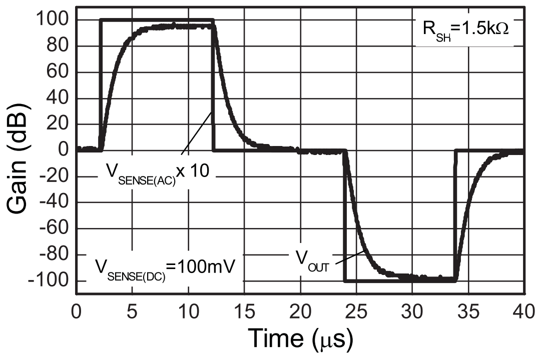


Frequency Response with constant R_{SH}

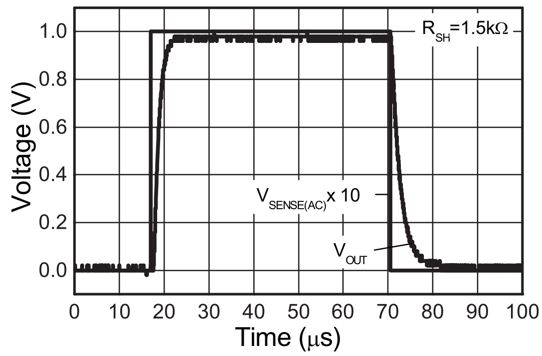
Test conditions unless otherwise stated: T_A = 25°C, G=100, R_G = 15k, $V_B = V_{SENSE+}$ (via R_{SH}), V_{SENSE} = 100mV.



Small Signal Step Response



Small Signal Step Response

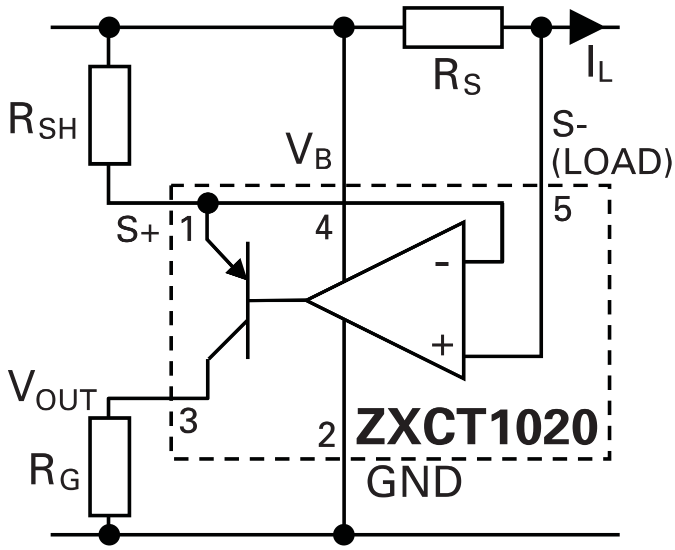


Large Signal Step Response

Application information

The ZXCT1020 has a V_B pin that is used to provide power to the current monitor. The maximum voltage applied to the ZXCT1020 must be applied to this pin. The S+ and S- pins are used to measure the current flowing to the load through the sense resistor. In normal use, the S+ is tied to V_B via a shunt resistor, R_H making the ZXCT1020 essentially line powered.

The ZXCT1020 has a programmable gain set by the ratio of two external resistors R_G and R_{SH}.



R_{SH} sets the transconductance whereas R_G set the gain and results in an output voltage defined as:

$$V_{OUT} = \frac{R_G}{R_{SH}} \times V_{SENSE}$$

Where $V_{SENSE} = R_{SENSE} \times I_L$

The ZXCT1020 has been tested to the same conditions as the ZXCT1021 giving an overall voltage gain of 10. The gain of the ZXCT1020 can be adjusted simply by varying R_G. So to achieve a gain of 50 R_G is increased from 15kΩ to 75kΩ. An alternative is to decrease R_{SH} from 1.5kΩ to 300Ω.

Decreasing R_{SH} increases the transconductance and, if for any given gain, reducing the R_{SH} will reduce the overall output impedance.

To achieve a gain of 100, for example, the following resistor values could be used:

$R_{SH} = 150$ $R_G = 15k$

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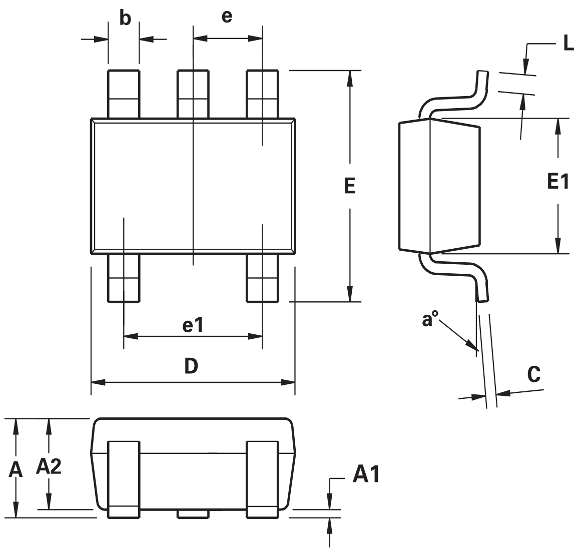
Package outline - SOT23-5



Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.90	1.45	0.0354	0.0570
A1	0.00	0.15	0.00	0.0059
A2	0.90	1.30	0.0354	0.0511
b	0.20	0.50	0.0078	0.0196
C	0.09	0.26	0.0035	0.0102
D	2.70	3.10	0.1062	0.1220
E	2.20	3.20	0.0866	0.1181
E1	1.30	1.80	0.0511	0.0708
e	0.95 REF		0.0374 REF	
e1	1.90 REF		0.0748 REF	
L	0.10	0.60	0.0039	0.0236
a°	0°	30°	0°	30°

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Definitions

Product change

Zetex Semiconductors reserves the right to alter, without notice, specifications, design, price or conditions of supply of any product or service. Customers are solely responsible for obtaining the latest relevant information before placing orders.

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   1. are intended to implant into the body

or

   2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labelling can be reasonably expected to result in significant injury to the user.

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ESD (Electrostatic discharge)

Semiconductor devices are susceptible to damage by ESD. Suitable precautions should be taken when handling and transporting devices. The possible damage to devices depends on the circumstances of the handling and transporting, and the nature of the device. The extent of damage can vary from immediate functional or parametric malfunction to degradation of function or performance in use over time. Devices suspected of being affected should be replaced.

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Zetex Semiconductors is committed to environmental excellence in all aspects of its operations which includes meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Zetex components are compliant with the RoHS directive, and through this it is supporting its customers in their compliance with WEEE and ELV directives.

Product status key:

"Preview"	Future device intended for production at some point. Samples may be available
"Active"	Product status recommended for new designs
"Last time buy (LTB)"	Device will be discontinued and last time buy period and delivery is in effect
"Not recommended for new designs"	Device is still in production to support existing designs and production
"Obsolete"	Production has been discontinued

Datasheet status key:

"Draft version"	This term denotes a very early datasheet version and contains highly provisional information, which may change in any manner without notice.
"Provisional version"	This term denotes a pre-release datasheet. It provides a clear indication of anticipated performance. However, changes to the test conditions and specifications may occur, at any time and without notice.
"Issue"	This term denotes an issued datasheet containing finalized specifications. However, changes to specifications may occur, at any time and without notice.

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